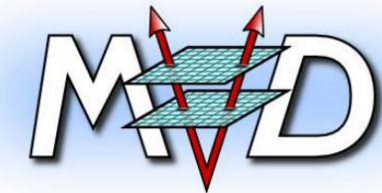




2019, München

# MIMOSIS, a CMOS sensor for the CBM -

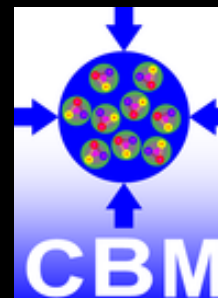


Michael DEVEAUX & Michal KOZIEL

On behalf of the CBM-MVD collaboration



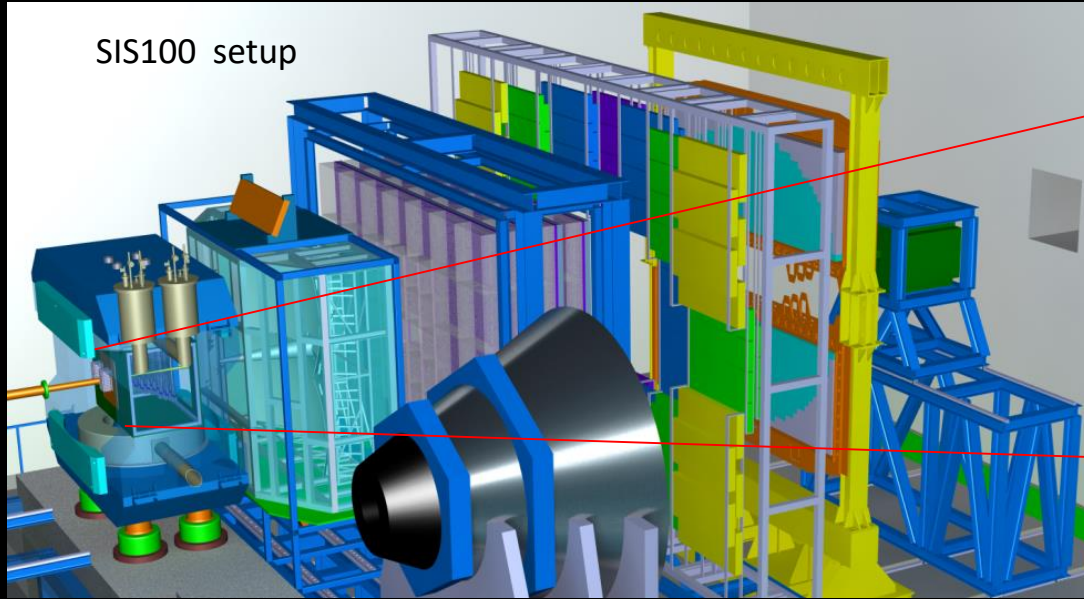
[koziel@physik.uni-frankfurt.de](mailto:koziel@physik.uni-frankfurt.de)



# Outline

- The CBM-Micro Vertex Detector: reminder
- Why another CMOS Pixel Sensor ?
- MIMOSIS-0
  - Sensor architecture
  - Test setup
  - Test results
  - Radiation tolerance
- Summary

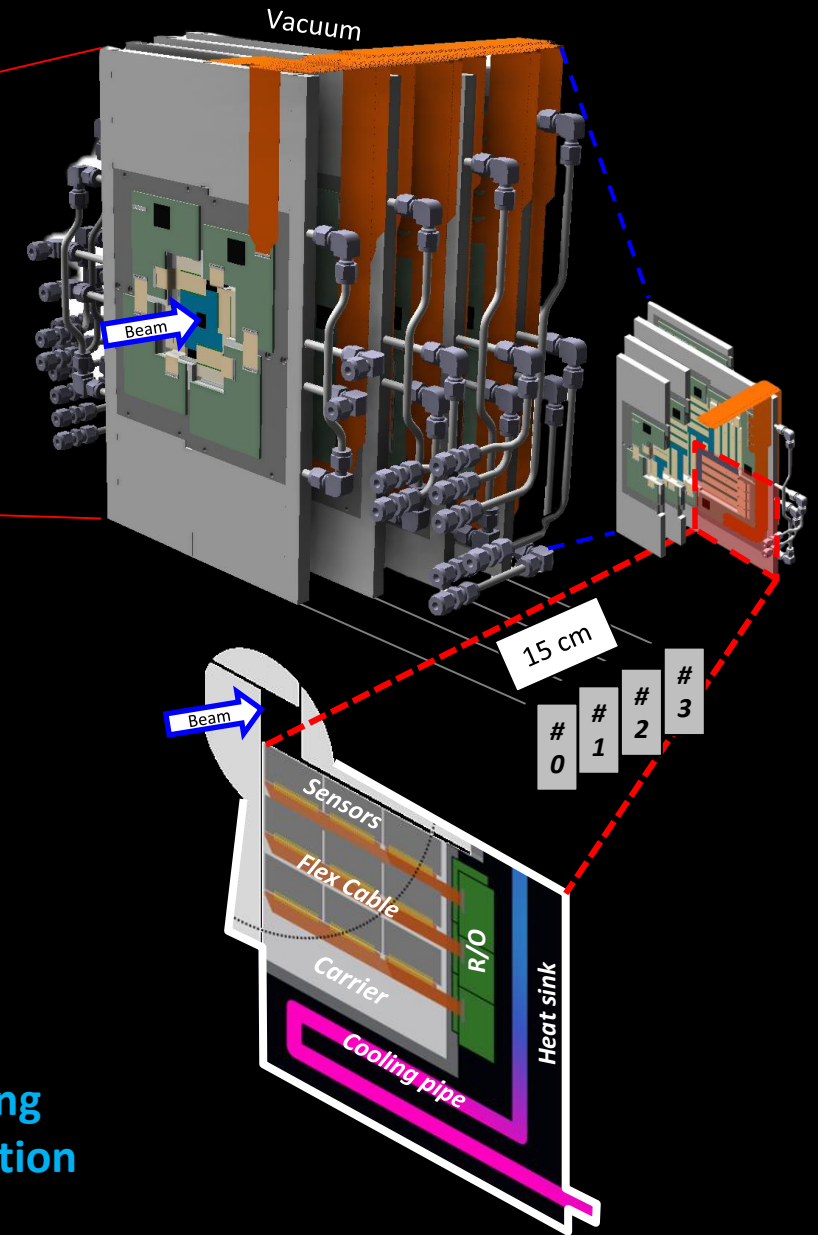
# The CBM-MVD: reminder



## CBM-MVD :

- Improve secondary vertex resolution (open charm)
- Tracking, focus low momentum particles
- Background rejection in di-electron measurements

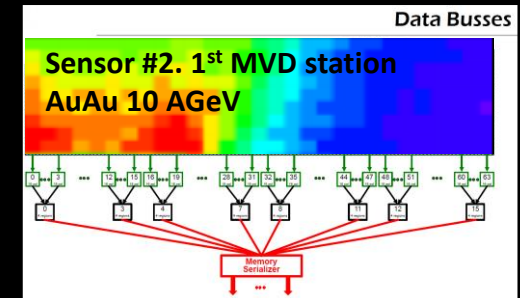
The MVD hosts highly granular silicon pixel sensors featuring low material budget, fast read-out, excellent spatial resolution and robustness to radiation environment.



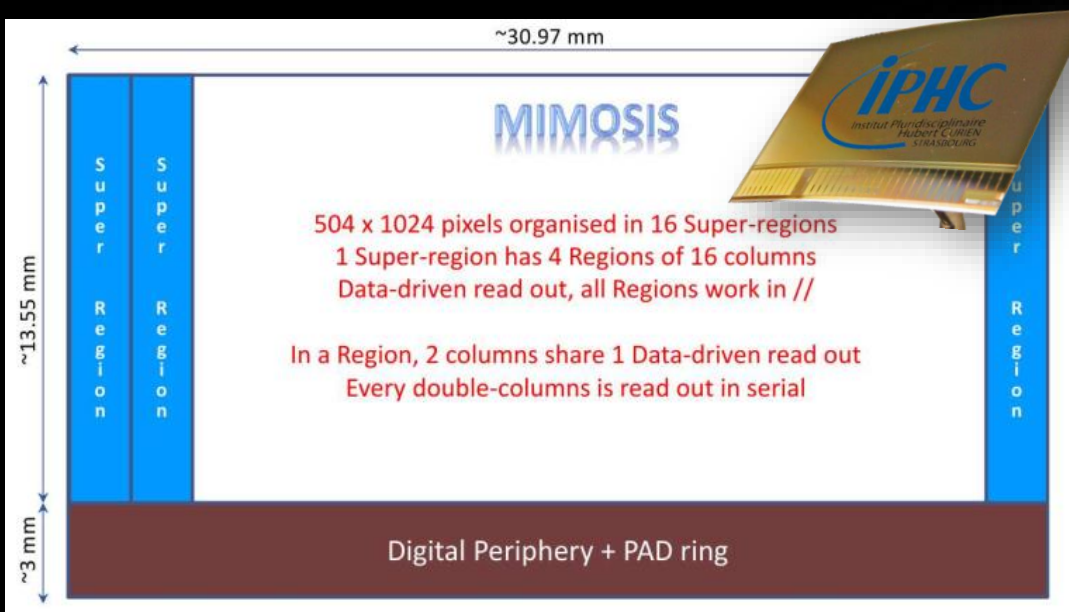
# MIMOSIS CPS development

Delta=electron dominated

	ALICE-ITS (IB)	CBM-MVD 1 <sup>st</sup> station
Radiation load TID	~270 krad	<b>3 Mrad</b>
Radiation load NIEL	~1.7x10 <sup>12</sup> n <sub>eq</sub> /cm <sup>2</sup>	<b>3x10<sup>13</sup> n<sub>eq</sub>/cm<sup>2</sup></b>
Power dissipation	50 mW/cm <sup>2</sup>	<b>&lt;300 mW/cm<sup>2</sup></b>
Operating temp.	T <sub>ROOM</sub>	<b>-10 °C</b>
Peak hit rate	~1.25x10 <sup>4</sup> /mm <sup>2</sup> /s	<b>7x10<sup>5</sup> /mm<sup>2</sup>/s</b> (x56 more than ITS)
Trigger	Yes	no



*There is no ready technical solution*



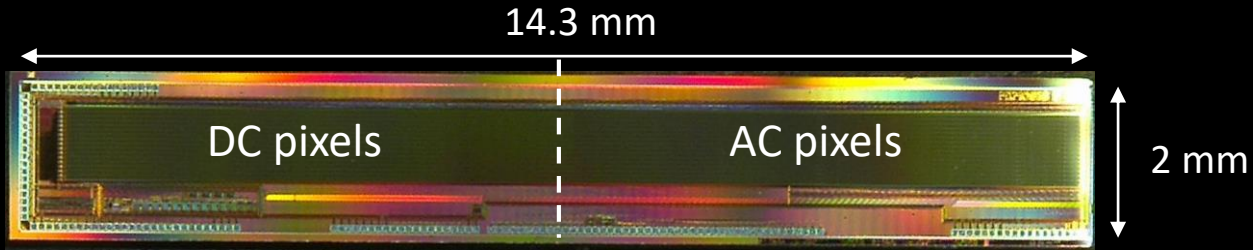
## Road map towards MIMOSIS:

- Small size pixel array -> MIMOSIS-0  
 Aims at selecting an optimum in-pixel architecture (AC vs. DC coupled pixels, performance of in-pixel amplifier and comparator) and studying the built-in priority encoder.
  - 1st full-size prototype - submission 2019
  - 2nd full-size prototype - submission 2020
  - MIMOSIS - submission 2021
- Today

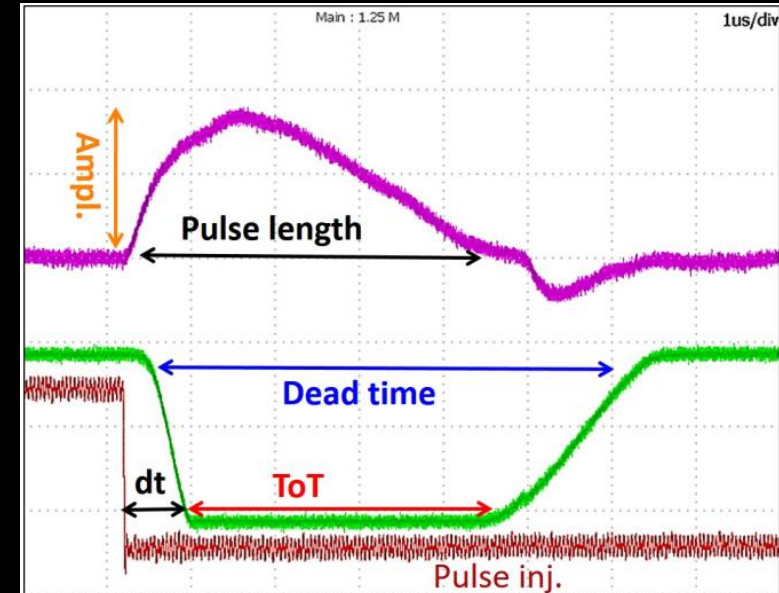
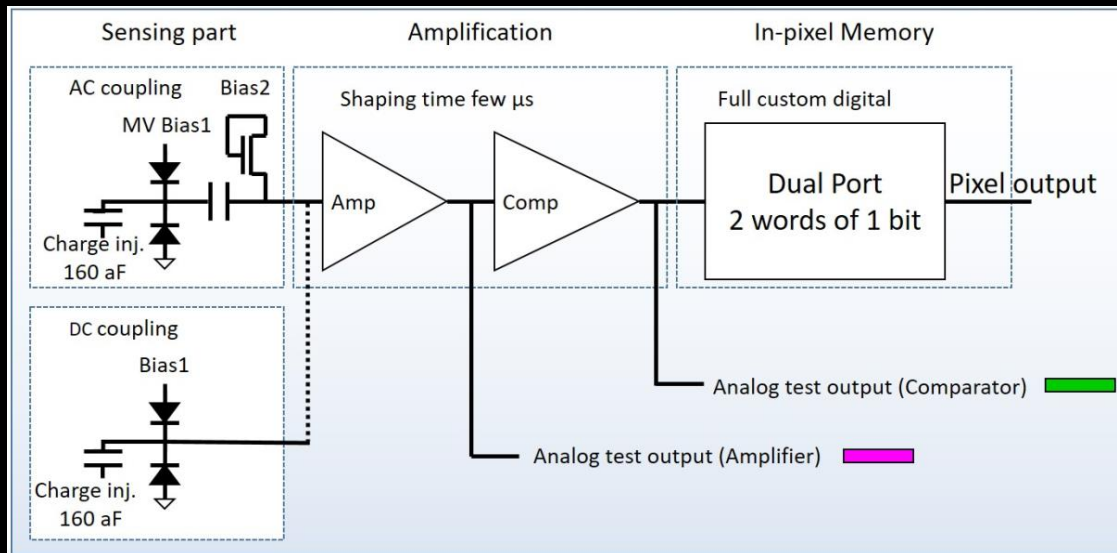
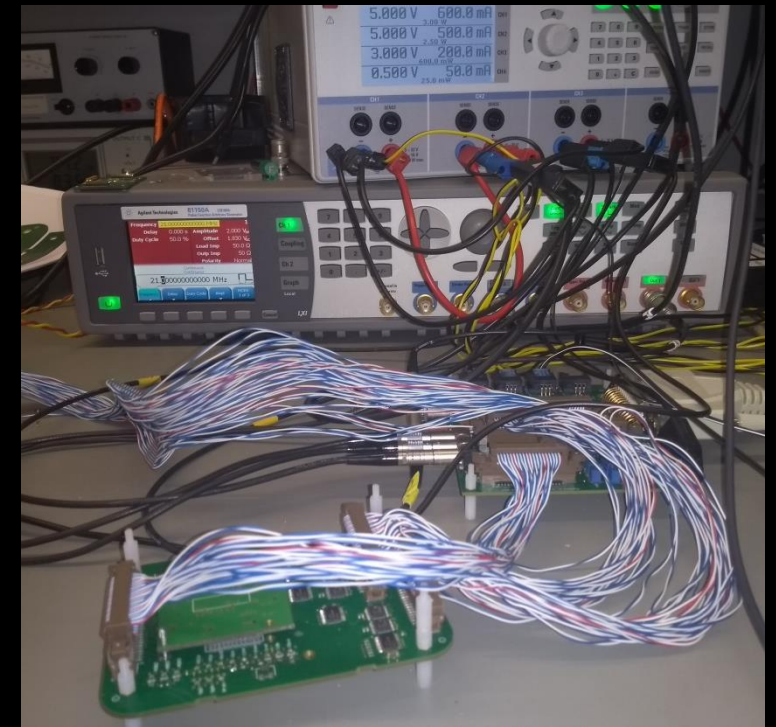
The CBM-MVD sensor will be based on the ALPIDE asynchronous read-out but with entirely new digital circuitry (signal processing and

# 1<sup>st</sup> prototype => MIMOSIS-0 sensor

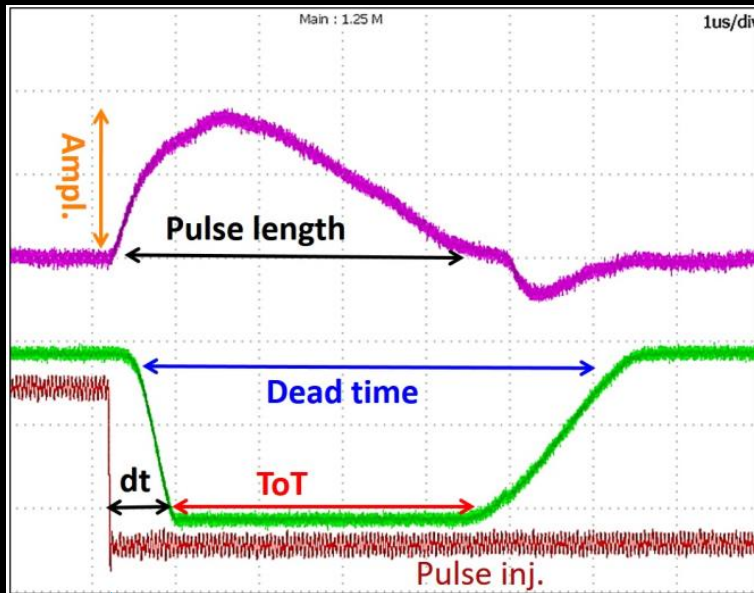
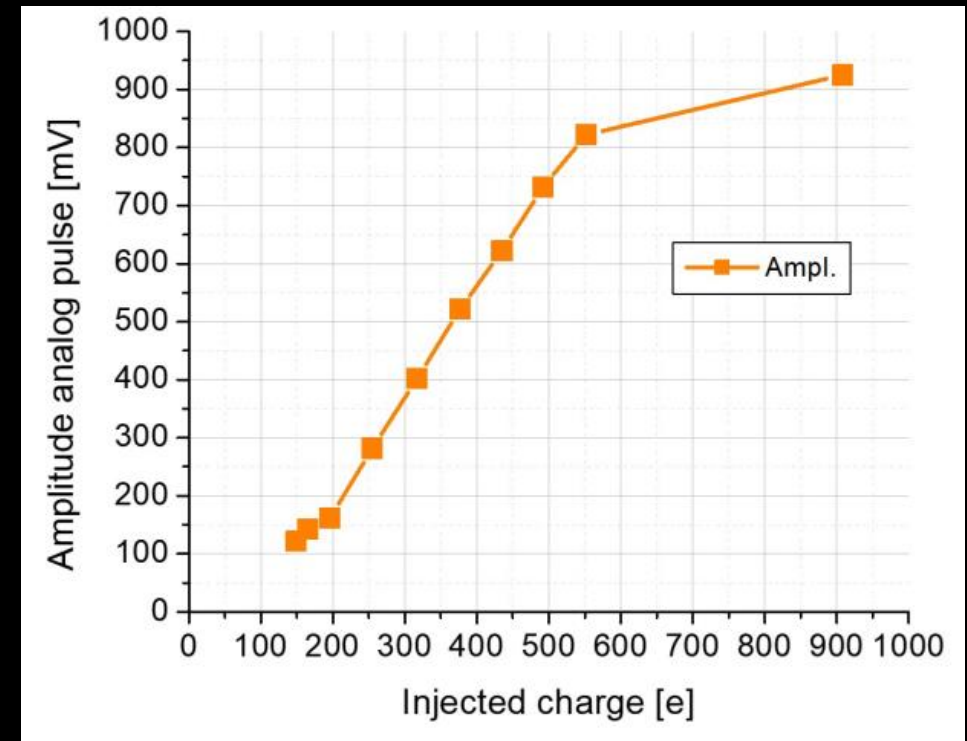
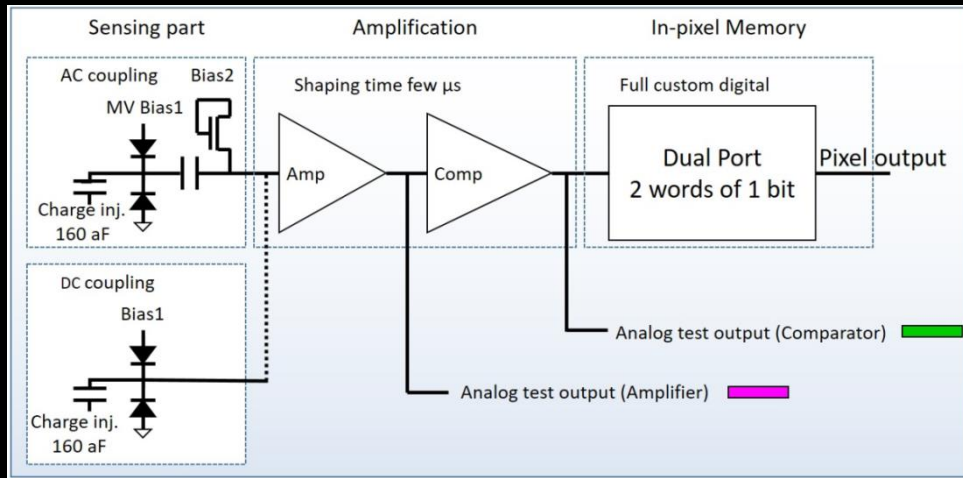
Aims at selecting an optimum in-pixel architecture (AC vs. DC coupled pixels, performance of in-pixel amplifier and comparator) and studying the built-in priority encoder.



- Pixel size: 26.88 x 30.24  $\mu\text{m}$
- EPI type / thickness: HR / 18  $\mu\text{m}$
- 13 8-bit DACs
- 16 col x 54 rows => 16128 pixels



# Properties of the amplification chain

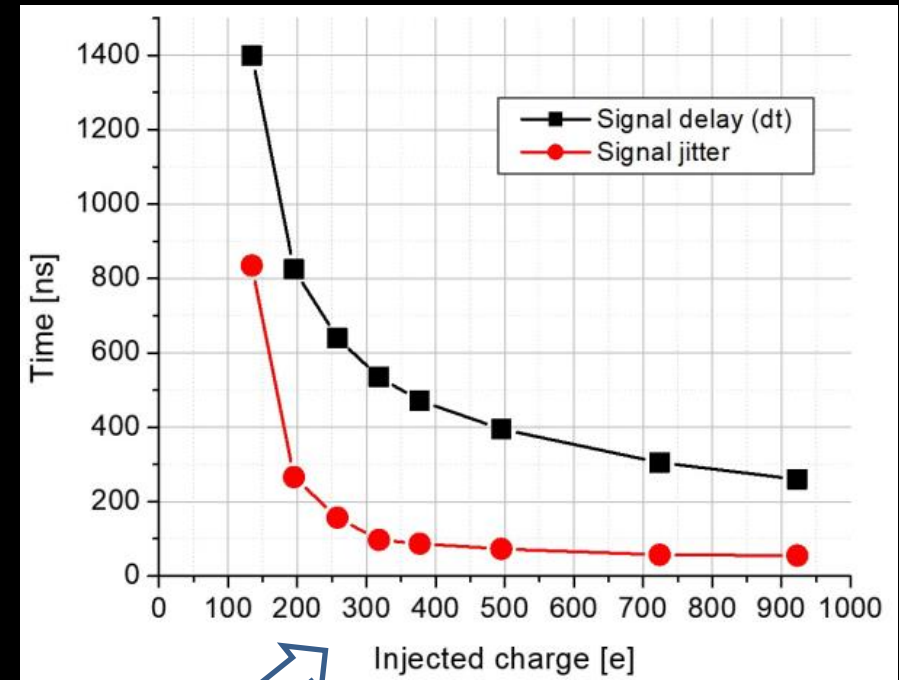
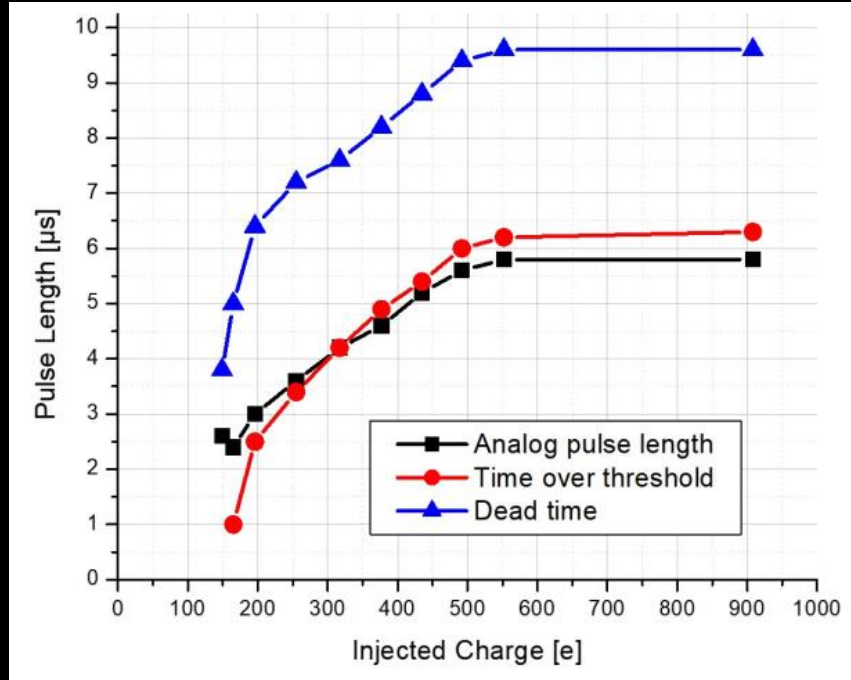
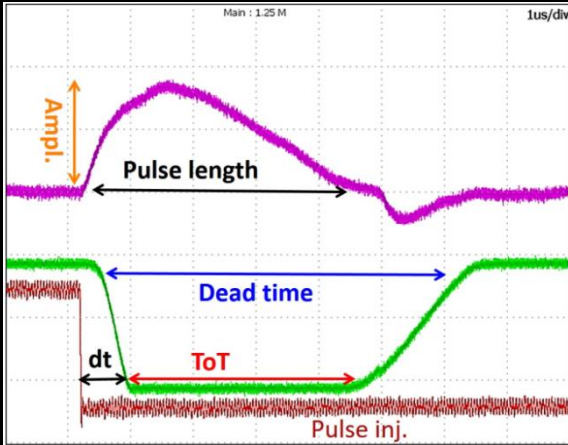


injection

- The amplifier is found linear in a range between roughly 150 e and 600 e. Below this value, the gain is reduced, which complicates choosing substantially lower thresholds independently of the noise.
- Above 600 e, the amplifier is intentionally saturated in order to restrict the pulse duration.

*We assume the capacity of the charge injection system to amount precisely its nominal value of  $C = 160$  aF*

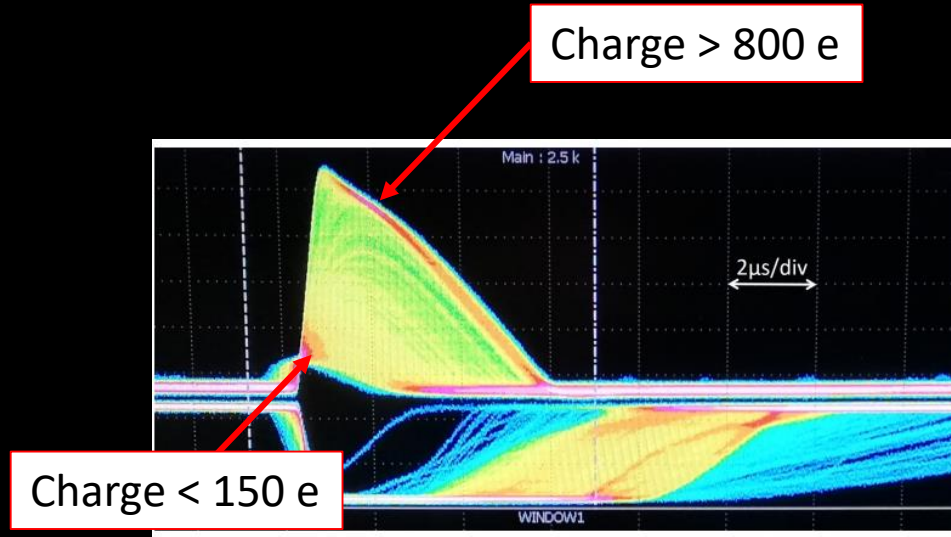
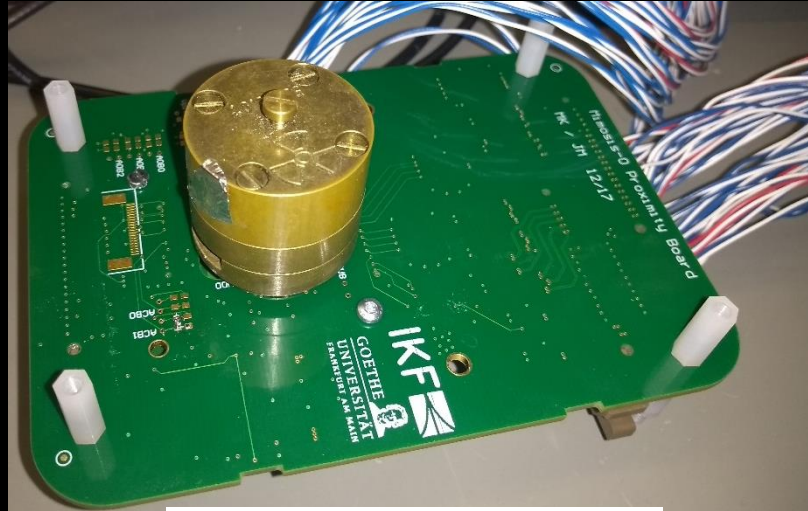
# Properties of the amplification chain



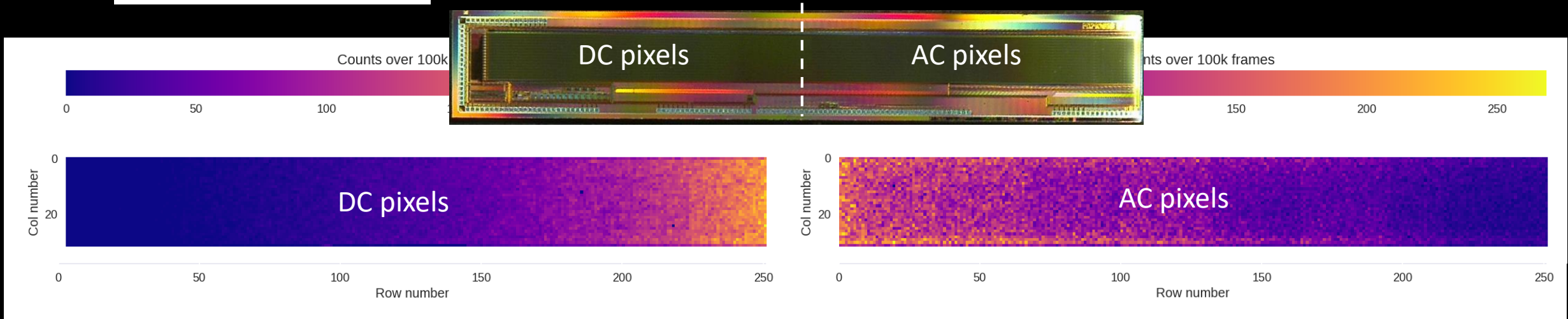
- The precise values vary by few 100 ns depending on the individual pixel and depend on the detailed settings of the eight current and voltage sources, which steer the pixels.
- Due to space constraints, all pixels share common voltage sources  $\Rightarrow$  an individual tuning of the pixels is not feasible.

- Time walk (variation of the delay as function of the signal amplitude) of  $\sim 1.4 \mu\text{s}$  and a jitter of  $0.85 \mu\text{s}$ , observed for the minimum charge injected.
- Still modest signal of  $> 300 e$  ENC  $\Rightarrow$  the time resolution might already be as good as  $0.6 \mu\text{s}$ , ...and may allow for further frame time reduction for limited occupancies.

# Sensitivity to radioactive source

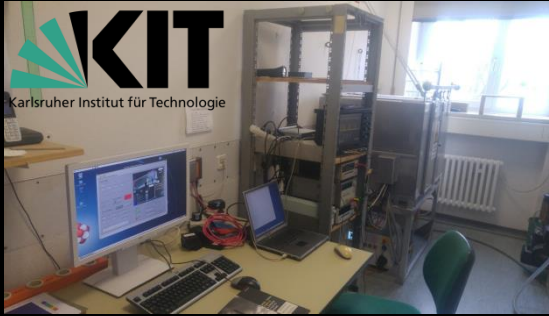


- In many cases, the 1640 e generated by the photon exceed the saturation limit of the pixel.
- Number of entries with low signal charge related to hits occurring far from the collection diode.



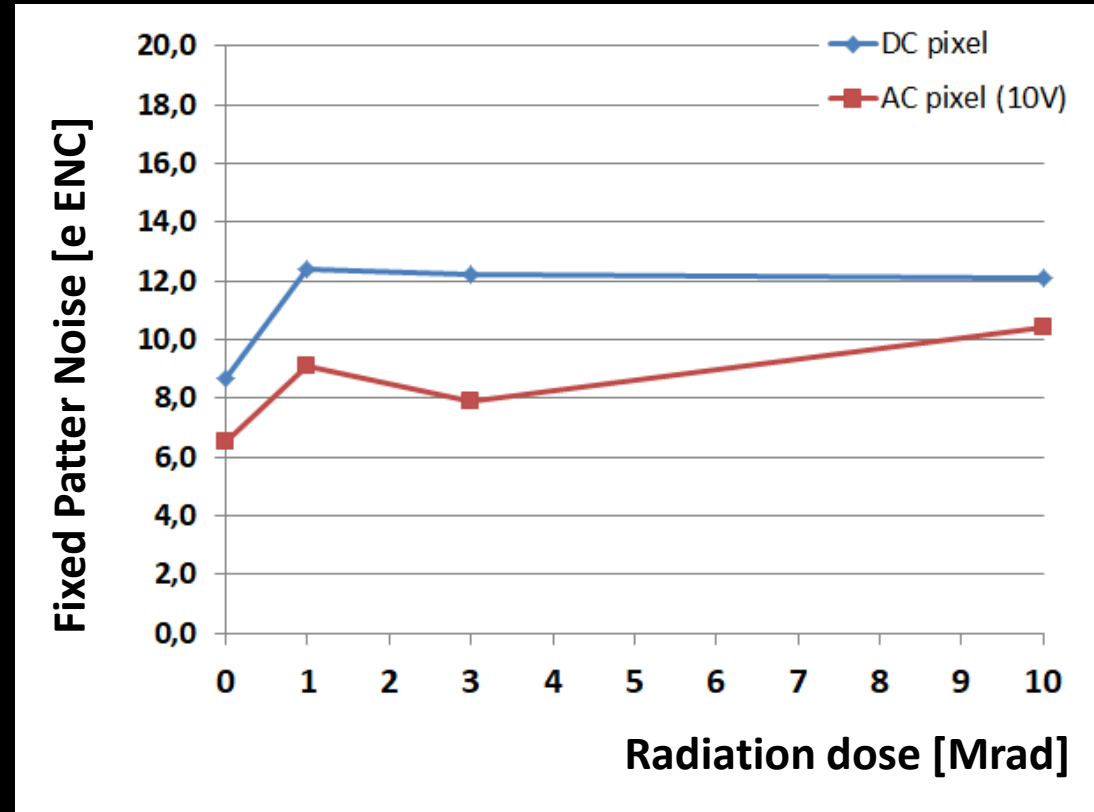
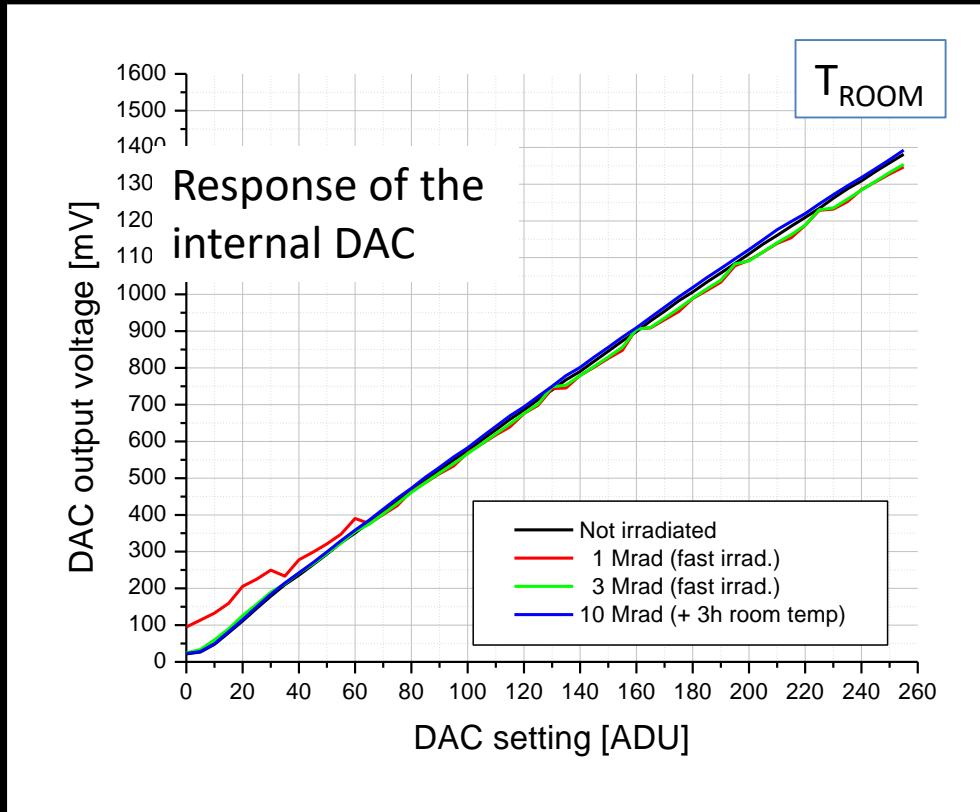


# Radiation tolerance studies



- X-Ray tube used thanks to KIT Karlsruhe
- Tolerance to ionizing radiation addressed
- Focus:
  - internal DACs
  - in-pixel circuitry

PRELIMINARY



# Summary and outlook

- CMOS Pixel Sensor for CBM Micro Vertex Detector is being developed
- The 1<sup>st</sup> prototype shown a successful integration of
  - Pixels hosting AC and DC coupled preamplifiers
  - Priority encoder
  - Slow control units
- The pulse shapes and lengths => it is conceptually suited to reach a  $\sim 1 \mu\text{s}$  time resolution (ambitioned  $5 \mu\text{s}$ ) in combination with a dead time of  $\sim 10 \mu\text{s}$ . Digital part to be adapted/tested.
- MIMOSIS-0 is currently being tested for its radiation tolerance
  - Preliminarily results have been presented
  - To do:
    - Leakage current measurements
    - The FPN and thermal noise will be studied in detail
    - AC vs. DC pixel ? => which pixel type for the upcoming submission
- First reticle size prototype is being prepared for a submission - mid 2019.